## NSN 5962-01-360-4022



Memory Microcircuit - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5962-01-360-4022 **Body Length:** 0.960 inches **Body Width:** 0.310 inches **Body Height:** 0.185 inches **Maximum Power Dissipation Rating:** 950.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Bipolar and burn in and high impedance and monolithic and programmed and schottky and tested to mil-std-883 and thin film and w/active pull-up and 3-state output **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Emitter-coupled logic **Input Circuit Pattern:** 13 input **Case Outline Source And Designator:** D-6 mil-m-38510 **Current Rating Per Characteristic:** 170.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder **Product Name:** Prom with active pullup and a third high-impedance state output **Voltage Rating And Type Per Characteristic:** 7.0 volts power source **Time Rating Per Chacteristic:** 125.00 nanoseconds propagation delay **Memory Device Type:** Prom **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 

N/a

18 printed circuit

Shelf Life:

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**Unit Of Measure:** 

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Demilitarization:

Yes - demil/mli

Fiig:

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